



# Subject Index

- A15 superconductor, 2  
 accelerators, 492  
 Ag/Bi-2212 magnets, 346–347  
 Ag/Bi-2212 tapes (*see* first generation HTS wire)  
 Ag/Bi-2212 wires (*see* first generation HTS wire)  
 Ag/Bi-2223 tapes (*see* first generation HTS wire)  
 $\text{AlSr}_2\text{Ca}_{n-1}\text{Cu}_n\text{O}_{2n+3}$  ( $\text{Al-}12(n-1)n$ ), 89  
 angle-resolved photoemission spectroscopy (ARPES), 158, 160, 426, 473, 475, 490  
 angular magnetoresistivity (AMR), 160  
 anisotropic superconductors, 83–84  
   anisotropy parameter, 84  
   anisotropic superconducting properties (cuprates), 165  
    $B_c$ ,  $B_{c2,ab}$ ,  $B_{c2,c}$ , 84  
   definition of anisotropic material properties, 83–84  
    $\lambda_{ab}$ ,  $\lambda_c$ , 83  
    $\kappa_{ab}$ ,  $\kappa_c$ , 84  
 antiferromagnetic domains, 160  
 antiferromagnetic ordering ( $\text{La}_2\text{CuO}_4$ ), 152–153  
 antiferromagnetism, 87  
 Arrhenius law, 207  
 Arrhenius plots of resistance, 213–215  
 artificial bicrystal grain boundaries, 189–190  
 atomic form factor, 106  
 attempt frequency (flux line hopping), 207  
  
 Ba-122, 459–461, 463, 467, 469, 473, 475, 477, 480–482, 490  
   coherence length, 475  
   critical current density (IBAD tape), 480  
   critical current density (PIT tape), 481  
   doping, 461, 464  
   energy gap, 473  
   lattice parameters, 470  
   layering scheme, 460  
   penetration depth, 475  
   phase diagram, 467  
   resistivity, 476  
   synthesis, 479  
   upper critical field, 474  
 band insulator, 21  
 band structures, 17–18  
   insulator, 17–18  
   metal, 17–18  
   semiconductor, 17–19  
 $B_c$ , 76  
 $B_{c1}$ , 76  
 $B_{c2}$ , 76  
   table, 76  
 BCS theory, 4, 40, 45–52, 71, 424, 426, 473  
 Bi-2212  
   bulk superconductors, 317–320  
   copper oxide blocks, 112, 116  
   crystal structure, 111–114  
     atom positions, 114  
   dependence of  $T_c$  on charge carrier density, 132–133  
   in-plane resistivity anisotropy, 233, 239–240  
   lattice parameters, 111  
   powder synthesis, 298–299  
   specific heat, 281–282, 284–285  
   tunneling spectra, 158  
   XRD pattern, 112



## 502 Subject Index

- Bi-22(n-1)n  
 $\text{Bi}_2\text{Sr}_2\text{Ca}_{n-1}\text{Cu}_n\text{O}_{2n+4}$  family, 89  
 crystal structure, 111–114  
 effect of number of  $\text{CuO}_2$  planes/ $\text{CuO}_2$   
 block on  $T_c$ , 135
- (Bi,Pb)-2223  
 bulk superconductors, 317–320  
 copper oxide blocks, 112  
 crystal structure, 111–114  
 lattice parameters, 111  
 powder synthesis, 299–303, (*see also*  
 synthesis of cuprate superconductor  
 powders)  
 pressure dependence of  $T_c$ , 140  
 specific heat, 281–285  
 thermal conductivity, 251–252  
 XRD pattern, 112
- Bitter technique, 204  
 Bloch functions, 17  
 Bloch theory, 22  
 body centering, 108, 113, 116  
 Bose–Einstein distribution law, 47  
 Bragg condition, 102, 105  
 Bragg scattering, 17  
 Bravais lattices, 103–104  
 Bravais lattice symbols, 103–104  
 Brillouin zones, 17–18  
 $\text{BSr}_2\text{Ca}_{n-1}\text{Cu}_n\text{O}_{2n+3}$  (B-12(n-1)n), 89  
 bulk cuprate superconductors, 293,  
 317–326  
 Bi-2212, 317–320  
 (Bi,Pb)-2223, 318–320  
 cold isostatic pressing, 318  
 manufacture, 293  
 melt cast process, 317–318  
 properties, 293  
 RE-123, 320–326  
 melt powder melt growth, 323  
 melt processing without thermal  
 gradient, 322  
 melt texture growth, 321  
 seed crystals, 323  
 trapped magnetic flux, 325–326
- Ca-122 ( $\text{CaFe}_2\text{As}_2$ ), 462, 465, 471, 472, 474,  
 476  
 critical temperature, 462  
 under pressure, 465  
 crystal structure, 472  
 lattice parameters, 475  
 resistivity, 476  
 upper critical field, 473
- Carnot efficiency, 6–7  
 carrier concentration (*see* charge carrier  
 density)
- Ce-1111, 461–463, 466, 468, 474  
 coherence length, 475  
 critical temperature, 462–463, 465  
 lattice parameters, 469  
 phase diagram, 466  
 synthesis, 479  
 upper critical field, 474
- characteristic length scales, 165–169, 473,  
 475  
 cuprate superconductors, 165–169  
 coherence length, 165–166  
 penetration depth, 165–166, 169  
 table, 167–168  
 Fe-based superconductors, 473, 475  
 charge carrier density ( $\text{CuO}_2$  planes), 93–96,  
 151, 166  
 cuprates, 166  
 charge carrier reservoirs, 88–91, 93, 94, 114,  
 119, 122, 203, 205, 219  
 charge stripes, 160–161  
 fluctuating charge stripes, 160  
 $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+x}$ , 160  
 $\text{La}_{2-x}\text{Ba}_x\text{CuO}_4$ , 214  
 compounds, 160  
 citrate pyrolysis, 294, 296  
 coated conductors (*see* second generation  
 HTS wire)  
 coherence length, 71, 73, 165–166, 188,  
 432–433, 475  
 cuprate superconductors, 165–168  
 Fe-based superconductors, 475  
 $\text{MgB}_2$ , 432, 433  
 collective pinning theories, 209  
 effective pinning potential, 209  
 conduction band, 17–18  
 conduction electrons, 13  
 conduction planes (*see*  $\text{CuO}_2$  planes)  
 Cooper pairs, 2, 4, 31, 45–47, 50–51, 71,  
 160  
 condensation energy, 71  
 wave function, 31, 50  
 phase of wave function, 50–51  
 phase coherence, 160  
 preformed, 160  
 Cooper-pair tunneling, 45



## Subject Index 503

- copper oxide blocks, 88–89, 110–112, 114, 116, 118–119, 124, 127, 131–133, 135–138, 145–146, 165, 187, 205, 206, 219, 220, 224, 293, 303, 313, 408
- Bi-2212, 112
- (Bi,Pb)-2223, 112
- HgBa<sub>2</sub>CuO<sub>4</sub>, 89
- La<sub>2</sub>CuO<sub>4</sub>, 88
- Tl-1223, 119, 121
- Tl-2201, 114–115
- Tl-2212, 116–117
- Tl-2223, 118
- Tl-2234, 118
- Tl<sub>2</sub>Ba<sub>2</sub>Ca<sub>2</sub>Cu<sub>3</sub>O<sub>10</sub>, 89
- YBa<sub>2</sub>Cu<sub>3</sub>O<sub>7</sub>, 88, 110–111
- corner junction, 155–157
- Josephson current, 155–157
- cost of cooling, 7
- Coulomb interaction, 49
- Coulomb repulsion, 21, 87
- creep effects, 83
- critical current, 174, 176–182
- definitions, 174, 176–178
- electric field criterion, 174, 176–177
- offset criterion, 176–177
- resistivity criterion, 178
- history effect (granular superconductors), 180–181
- polycrystalline cuprate superconductors, 178–182
- critical current density ( $j_c$ ), 7, 47
- required for applications, 6
- critical current density (cuprates), 182–191, 193, 319–320, 323–325
- across artificial grain boundaries, 191
- angle dependence of  $j_c$ , 187–188
- anisotropy of  $j_c$ , 185, 186
- bulk cuprate superconductors, 182–183
- $j_c$  (Bi-based superconductors), 319–320
- $j_c$  (RE-123 bulk superconductors), 323–325
- superconducting films (cuprates), 183–188
- $j_c$  at zero applied field, 184
- critical current density (Fe-based superconductors), 477–482
- critical current density (MgB<sub>2</sub> wires and tapes), 441–444
- critical magnetic field ( $B_c$ ), 27–28
- critical temperature ( $T_c$ )
- Al, 4
- BCS formula, 48
- Cs<sub>3</sub>C<sub>60</sub>, 6
- cuprate superconductors, 90–93, 131–143
- dependence on formal Cu valence, 132
- Bi-2212, 132–133
- La-214, 132–133
- Hg-1201, 134
- Hg-1212, 134
- Hg-1223, 134
- Y-123, 132–133
- Y,Ca-123, 132–133
- dependence on number of CuO<sub>2</sub> planes/CuO block, 131
- table, 92–93
- effect of pressure on  $T_c$ , 138–146
- effect of number of CuO<sub>2</sub> planes/CuO block, 135–138
- Bi-22( $n-1$ ) $n$ , 135
- (Cu,C)-12( $n-1$ ) $n$ , 136
- (Cu,Cr)-12( $n-1$ ) $n$ , 136
- Hg-12( $n-1$ ) $n$ , 136
- (Hg,Cr)-12( $n-1$ ) $n$ , 136
- (Hg,Tl)-22( $n-1$ ) $n$ , 135
- Tl-22( $n-1$ ) $n$ , 135
- definitions of  $T_c$ , 23–24
- Hg, 3
- HgBa<sub>2</sub>Ca<sub>2</sub>Cu<sub>3</sub>O<sub>8+ $\delta$</sub> , 2, 5
- Hg<sub>0.8</sub>Tl<sub>0.2</sub>Ba<sub>2</sub>Ca<sub>2</sub>Cu<sub>3</sub>O<sub>8+x</sub>, 5
- high-temperature superconductors, 23
- In (under pressure), 41
- iron-based superconductors, 461–467
- dependence on anion height, 463
- dependence on Fe-As-Fe bond angle, 462, 464
- effect of chemical pressure, 463, 465
- pressure dependence, 465
- table, 462
- K<sub>3</sub>C<sub>60</sub>, 2, 6
- (La,Ba)<sub>2</sub>CuO<sub>4+ $\delta$</sub>  (under pressure), 41
- La(O<sub>1-x</sub>F<sub>x</sub>)FeAs, 2
- LiTi<sub>2</sub>O<sub>4</sub>, 6
- low-temperature superconductors, 22, 29, 30
- MgB<sub>2</sub>, 2, 6
- Nb<sub>3</sub>Ge, 2, 4
- NbN, 2, 3



## 504 Subject Index

critical temperature ( $T_c$ ) (continued)

Pb, 3  
 SmO<sub>0.85</sub>FeAs, 6  
 Sn, 3  
 SrTiO<sub>3</sub>, 6  
 superconducting elements, 29  
   under high pressure, 30  
 V<sub>3</sub>Si, 2  
 YBa<sub>2</sub>Cu<sub>3</sub>O<sub>7- $\delta$</sub> , 2, 4, 87  
 crystal structure  
   Bi-22( $n-1$ ) $n$ , 111–114  
     Bi-2212, 111–114  
       atom positions, 114  
     (Bi,Pb)-2223, 111–114  
       atom positions, 114  
   HgBa<sub>2</sub>Ca <sub>$n-1$</sub> Cu <sub>$n$</sub> O<sub>2 $n+2$</sub> , 121–125  
     Hg-1201, 121–123  
       atom positions, 123  
     Hg-1212, 124–125  
       atom positions, 125  
     Hg-1223, 124–125  
       atom positions, 125  
     Hg-1234, 124–125  
       atom positions, 125  
     Hg-1245, 124–125  
 iron-based superconductors, 459–460,  
   467–472  
     CaFe<sub>2</sub>As<sub>2</sub> (Ca-122), 472  
     LaOFeAs (La-1111), 472  
     lattice parameters, 459–460, 469  
       (1 1 1) family, 468, 469  
       Ba-122, 469  
       FeSe, 469  
       LiFeAs, 469  
     layering schemes, 459–460  
       (1 1) family, 459–460  
       (1 1 1) family, 459–460  
       (1 1 1) family, 459–460  
       (1 2 2) family, 459–460  
 La<sub>2</sub>CuO<sub>4</sub>, 107–109  
   atom positions, 109  
 MgB<sub>2</sub>, 424  
 Tl-1223, 119–121  
   atom positions, 121  
 Tl-2201, 114–116  
   atom positions, 116  
 Tl-2212, 116–117  
   atom positions, 117  
 Tl-2223, 116, 118–120  
   atom positions, 120

Tl-2234, 118–120  
   atom positions, 120  
 YBa<sub>2</sub>Cu<sub>3</sub>O<sub>7- $\delta$</sub> , 108–111  
   atom positions, 111  
 CuBa<sub>2</sub>Ca <sub>$n-1$</sub> Cu <sub>$n$</sub> O<sub>2 $n+2$</sub>  (Cu-12( $n-1$ ) $n$ ), 90  
 (Cu,C)Ba<sub>2</sub>Ca <sub>$n-1$</sub> Cu <sub>$n$</sub> O<sub>2 $n+3$</sub>   
   ((Cu,C)-12( $n-1$ ) $n$ ), 90  
 CuO chains (REBa<sub>2</sub>Cu<sub>3</sub>O<sub>7</sub>), 89, 109–110  
 CuO<sub>2</sub> layers (*see* CuO<sub>2</sub> planes)  
 CuO<sub>2</sub> planes, 87–91, 93–94, 96–97, 108,  
   110–112, 135, 138  
   inner CuO<sub>2</sub> planes, 135  
   outer CuO<sub>2</sub> planes, 135  
     nonuniform hole distribution among  
     planes, 138  
 CuO<sub>2</sub> sheets (*see* CuO<sub>2</sub> planes)  
 cuprate superconductor films, 393–416  
   deposition techniques  
     Bi-based HTS films, 394  
       table, 395–397  
     Hg-based HTS films, 397, 400–404  
       table, 401–403  
     RE-123 HTS films, 404–407  
       table, 405–407  
     Tl-based HTS films, 394, 397  
       table, 398–400  
   multilayers (ultrathin films), 407–412  
     critical temperature, 410  
     MgO/Pr-123/Y-123, 407–408  
     SrTiO<sub>3</sub>/Pr-123/Y-123/Pr-123,  
       408–409  
     superlattices (La,Sr)<sub>2</sub>CuO<sub>4</sub>/La<sub>2</sub>CuO<sub>4</sub>,  
       410–412  
       critical temperature, 411–412  
     strain effects, 412–416  
     Tl-Hg cation exchange, 400  
 cuprate superconductors  
   AlSr<sub>2</sub>Ca <sub>$n-1$</sub> Cu <sub>$n$</sub> O<sub>2 $n+3$</sub>  (Al-12( $n-1$ ) $n$ ), 89  
   BSr<sub>2</sub>Ca <sub>$n-1$</sub> Cu <sub>$n$</sub> O<sub>2 $n+3$</sub>  (B-12( $n-1$ ) $n$ ), 89  
   Bi<sub>2</sub>Sr<sub>2</sub>Ca <sub>$n-1$</sub> Cu <sub>$n$</sub> O<sub>2 $n+4$</sub>  (Bi-22( $n-1$ ) $n$ ), 89  
   cation disorder, 94  
   CuBa<sub>2</sub>Ca <sub>$n-1$</sub> Cu <sub>$n$</sub> O<sub>2 $n+2$</sub>  (Cu-12( $n-1$ ) $n$ ),  
     90  
   (Cu,C)Ba<sub>2</sub>Ca <sub>$n-1$</sub> Cu <sub>$n$</sub> O<sub>2 $n+3$</sub>   
     ((Cu,C)-12( $n-1$ ) $n$ ), 90  
   doping (*see also* charge carrier  
     density), 93–96  
   electron-doped cuprate  
     superconductors, 95  
   Nd<sub>2- $x$</sub> Ce <sub>$x$</sub> CuO<sub>4</sub>, 95



- $\text{Pr}_{2-x}\text{Ce}_x\text{CuO}_{4-\delta}$ , 95  
 $\text{Sm}_{2-x}\text{Ce}_x\text{CuO}_4$ , 95  
 $\text{GaSr}_2\text{Ca}_{n-1}\text{Cu}_n\text{O}_{2n+3}$  (Ga-12( $n-1$ ) $n$ ), 90  
 $\text{HgBa}_2\text{Ca}_2\text{Cu}_3\text{O}_{8+\delta}$  (*see also* Hg-1223), 2, 5  
 $\text{HgBa}_2\text{Ca}_{n-1}\text{Cu}_n\text{O}_{2n+2}$   
 (Hg-12( $n-1$ ) $n$ ), 89  
 La-214, 89  
 $\text{La}_{2-x}\text{Ba}_x\text{CuO}_4$ , 6, 87  
 oxygen content, 94  
 RE-123, 89  
 self-doping, 94  
 Tl-12( $n-1$ ) $n$  ( $\text{TlM}_2\text{Ca}_{n-1}\text{Cu}_n\text{O}_{2n+3}$ )  
 (M = Ba or Sr), 89  
 Tl-2201 ( $\text{Tl}_2\text{Ba}_2\text{CuO}_6$ ), 89  
 Tl-2212 ( $\text{Tl}_2\text{Ba}_2\text{CaCu}_2\text{O}_8$ ), 89  
 Tl-2223 ( $\text{Tl}_2\text{Ba}_2\text{Ca}_2\text{Cu}_3\text{O}_{10}$ ), 89  
 Tl-22( $n-1$ ) $n$  ( $\text{Tl}_2\text{Ba}_2\text{Ca}_{n-1}\text{Cu}_n\text{O}_{2n+4}$ ), 89  
 Y-123 ( $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$ ), 2, 4, 87  
 current leads, 249, 293, 317, 320, 492  
 current-voltage characteristic (NIN junction), 54  
 current-voltage characteristic (NIS junction), 58  
 current-voltage characteristic (SIS junction), 59  
 current-voltage characteristic (vortex glass), 217–218  
  
 de Broglie relation, 101  
 de Broglie relationship, 52  
 Debye frequency, 35, 48–50, 279  
 Debye model, 279  
 Debye temperature, 35, 40, 279, 434  
 density of energy states, 15, 40, 47–48, 159  
   density of states (superconducting energy gap), 47  
   *d*-wave superconductor, 159  
   *s*-wave superconductor, 159  
 differential thermal analysis (DTA), 341  
 Dimos experiment, 189  
 doping, 93–96, 461, 463, 464  
   cuprates, 93–96  
   Fe-based, 461, 463, 464  
 drift velocity (electrons), 19  
 Dulong–Petit value (specific heat), 434  
*d*-wave superconductor, 159, 162  
  
 effective mass (electrons), 19–20  
 Ehrenfest relationship, 144  
  
 Einstein specific heat, 283  
 electrical conductivity, 19–20  
 electrical resistance, 13–21  
   gold, 1  
   metals, 1  
   mercury, 1–3  
   platinum, 1  
 electron concentration, 16  
 electron-doped cuprate superconductors, 95  
    $\text{Nd}_{2-x}\text{Ce}_x\text{CuO}_4$ , 95  
    $\text{Pr}_{2-x}\text{Ce}_x\text{CuO}_{4-\delta}$ , 95  
    $\text{Sm}_{2-x}\text{Ce}_x\text{CuO}_4$ , 95  
 electron-electron interaction, 87  
 electron-phonon coupling, 49, 490  
 electron-phonon coupling constant, 49  
   intermediate coupling, 49  
   strong coupling, 49  
   weak coupling, 49  
 electron-phonon interaction, 20–21, 45–48, 50, 424, 450  
 energy gap (semiconductors), 17–18  
 energy gap (superconductor), 47  
   antinodal gap, 160  
   BCS theory, 47–49  
   cuprates, 153  
     maximum gap, 169–171  
     table, 170  
     spatial variation, 170  
   density of states close to  $E_F$ , 47  
 Fe-based superconductors, 471, 473  
   ARPES, 473  
   point-contact Andreev-reflection spectroscopy (PCAR), 473  
   table, 473  
   nodal gap, 160  
   nodes, 154  
   relation with  $T_c$  (BCS theory), 48  
   symmetry, 153–154  
 engineering critical current density, 340, 370  
 extended *s*-wave gap, 490  
  
 fault current limiters, 293, 317, 339, 493  
 Fermi-Dirac distribution function, 15, 265  
 Fermi energy, 15  
 Fermi gas, 20  
 Fermi liquid, 20–21  
 Fermi liquid behavior (overdoped cuprates), 162  
 Fermi liquid theory, 20, 151  
 Fermi surface ( $\text{CuO}_2$  planes), 159



## 506 Subject Index

- Fermi wave number, 15  
 FeSe, 469–471  
 FeTe, 471  
 flux creep resistance, 212  
   activation energy, 216, 217  
 flux flow resistivity, 81–82, 203  
 flux-line lattice, 204  
    $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+x}$ , 204  
    $\text{YBa}_2\text{Cu}_3\text{O}_7$ , 204, 205  
 flux-line lattice melting, 171–172  
 flux lines, 83, 203  
 flux pinning, 79, 83, 203–226, 371  
    $\text{BaZrO}_3$  nanorods, 371  
 flux quantization, 2, 4, 50–52  
 flux quantum, 52, 77  
 field penetration (thin superconducting slab), 32–34  
 formal valence (Cu in cuprate superconductors), 94, 96, 97  
   formal valence at maximum  $T_c$ , 132, 135  
 free electrons (see also conduction electrons), 13–14  
   density of states, 16  
   energy eigen values, 14  
   momentum, 14  
   wave function, 14  
   wave vector, 14  
  
 $\text{GaSr}_2\text{Ca}_{n-1}\text{Cu}_n\text{O}_{2n+3}$  (Ga-12( $n-1$ ) $n$ ), 90  
 generators, 492  
 generic phase diagram (hole-doped cuprates), 151–153, 161  
   carrier concentration, 152  
   optimum carrier concentration (maximum  $T_c$ ), 161  
   overdoped, 162  
 generic phase diagram (iron-based superconductors), 459, 465–467  
   parent compounds, 459  
   phase diagram ((1 1 1) family), 465–466  
   phase diagram ((1 2 2) family), 467  
 Gibbs free energy, 36  
 Ginzburg–Landau equations, 71  
 Ginzburg–Landau (GL) parameter, 73  
   cuprates, 166, 194  
   table, 167–168  
    $\text{MgB}_2$ , 433  
   table, 74  
 Ginzburg–Landau (GL) theory, 4, 70–73  
 grain alignment, 344  
  
 grain-boundary weak links, 180, 188–191, 423  
 granular cuprate superconductor, 180  
 granularity, 180  
  
 Hall coefficient, 95  
 Hall effect, 94–95  
 Hall voltage, 94–95  
 helium liquefaction, 1, 2  
 Hg-1201  
   crystal structure, 121–123  
   atom positions, 123  
   dependence of  $T_c$  on charge carrier density, 134  
   lattice parameters, 123  
   powder synthesis, 311–313  
   pressure dependence of  $T_c$ , 142  
   specific heat, 283  
   XRD pattern, 122  
 Hg-1212  
   crystal structure, 124–125  
   atom positions, 125  
   dependence of  $T_c$  on charge carrier density, 134  
   lattice parameters, 125  
   powder synthesis, 313–314  
   pressure dependence of  $T_c$ , 142  
   XRD pattern, 123  
 Hg-1223  
   crystal structure, 124–125  
   atom positions, 125  
   dependence of  $T_c$  on charge carrier density, 134  
   lattice parameters, 125  
   powder synthesis, 313, 315–317  
   pressure dependence of  $T_c$ , 142  
   record  $T_c$  value, 5  
 high-angle grain boundaries, 190  
 high-temperature superconductivity, 4  
 high-temperature superconductor (HTS) wires  
   first-generation HTS wire, 340–361  
   Ag/Bi-2212-coated conductors, 347  
   Ag/Bi-2212 wires and tapes, 341–353  
   bubble formation, 346  
   critical current densities, 349–353  
   dip-coating, 347, 348  
   electrophoretic deposition, 347  
   heat treatment schedules, 343–345, 348



## Subject Index 507

- melt processing, 346
- overpressure processing, 346
- partial melting, 341, 344
- partial melting temperature, 344
- phase assembly, 346
- residual carbon content, 346
- round wire, 341
- step solidification, 344
- tape casting, 347–348
- void swelling, 345
- Ag/Bi-2223 tapes, 341, 351–361
  - average particle size, 356–357
  - c*-axis texture, 354, 356, 361
  - colony structure, 356
  - critical current, 358–359
  - critical current normalized to  $j_c$  (77 K, sf), 360
  - deformation studies, 357
  - heat treatment atmosphere, 354
  - high pressure processing, 357, 358
  - lead substitution, 354
  - powder-in-tube method, 352
  - residual carbon content, 356
  - rolling, 353
- powder-in-tube (PIT)
  - method, 341–342, 352
- second-generation HTS wire (coated conductors), 339–340, 361–381
  - biaxial texture, 361
  - buffer layer architectures, 365–369
  - buffer layers, 364
  - chemical vapor deposition, 362
  - critical current densities, 370–377
    - angle dependence, 373, 375–377
      - 77 K, 1 T, 375
      - 20–50 K, 3 T, 376
      - 4.2 K, 60 K at high fields
        - anisotropy, 371, 377
    - field dependence at 77 K, 370–372
    - field dependence (4.2–65 K), 371, 373
    - temperature-dependence, 371, 374
  - electron beam evaporation, 362, 364
  - flux pinning, 371
    - BaZrO<sub>3</sub> nanorods, 371
  - inclined substrate deposition (ISD), 363
  - ion-beam-assisted deposition (IBAD), 362
    - buffer layer sequences, 370
- lengthy coated conductors, 379–381
- microstructure, 377–379
- pulsed laser deposition (PLD), 362, 363
- RABiTS (Rolling Assisted Biaxially Textured Substrates), 363–364
  - film sequences, 370
  - yield strength of Ni, 369
  - yield strength of Ni-W, 369
- RE-123, 347
- weak-link problem, 361
- X-ray  $\phi$  scans, 362
- holes (in cuprate superconductors), 94
- hopping rate (flux lines), 207
- HTS insert coil, 340
- inclined substrate deposition (ISD), 363
- intrinsic pinning (cuprates), 203, 205–207
- iodometric titration, 96
- ion-beam-assisted deposition (IBAD), 362
  - buffer layer sequences, 370
- iron-based superconductors, 459–482
  - critical current densities, 477, 480–482
  - critical temperatures, 461–467
    - dependence on anion height, 463
    - dependence on Fe-As-Fe bond angle, 462, 464
  - effect of chemical pressure, 463, 465
  - pressure dependence, 465
  - table, 462
- crystal structures, 459, 467–471
  - CaFe<sub>2</sub>As<sub>2</sub> (Ca-122), 472
  - LaOFeAs (La-1111), 472
  - layering schemes, 459–460
    - (1 1) family, 459–460
    - (1 1 1) family, 459–460
    - (1 1 1 1) family, 459–460
    - (1 2 2) family, 459–460
  - lattice parameters, 459–460
    - (1 1 1 1) family, 469
    - Ba-122, 469
    - FeSe, 469
    - LiFeAs, 469
- dependence of  $T_c$  on doping, 461, 463, 464
- doping, 461
- FeAs layer, 460
- iron-chalcogenide (FeCh) layers, 460
- iron-pnictides, 6, 459–460
- La(O<sub>1-x</sub>F<sub>x</sub>)FeAs (La-1111), 2, 6



## 508 Subject Index

- iron-based superconductors (*continued*)
- lower critical field, 473–474
    - table 474
  - magnetic instability, 459
  - parent compounds, 459
  - phase diagram ((1 1 1 1) family), 465–466
  - phase diagram ((1 2 2) family), 467
  - physical properties, 471–477
    - characteristic length scales, 473, 475
      - table (penetration depth, coherence length), 475
    - energy gap, 471, 473
      - ARPES, 473
      - point-contact Andreev-reflection spectroscopy (PCAR), 473
      - table, 473
    - resistivity, 475–477
  - Sm(O<sub>1-x</sub>F<sub>x</sub>)FeAs (*see* Sm-1111)
  - SmO<sub>0.85</sub>FeAs (*see* Sm-1111)
  - spin density wave (antiferromagnetic ordering), 465–467
  - structural instability, 459
  - synthesis, 477
    - table, 478–480
  - upper critical field, 473–474
    - table, 474
- irreversibility field ( $B_{irr}$ ), 171, 218–221
- anisotropy, 219, 221
- irreversibility line, 171–174, 194, 203, 216–226
- after irradiation, 222, 225, 226
- irreversibility temperature, 172–173
- isotope effect ( $T_c$ ), 50–51, 424–425
- isotope effect exponent, 50–51
  - MgB<sub>2</sub>, 424–425
- Josephson AC current, 61–62
- Josephson DC current, 59–61
- Josephson–Fraunhofer diffraction pattern, 64
- Josephson–Fraunhofer interference, 64
- Knight shift, 137
- La-1111 (LaO<sub>1-x</sub>F<sub>x</sub>FeAs), 2, 6, 459–463, 469, 472, 474–476, 478
- coherence length, 475
  - critical temperature, 461–463
  - crystal structure, 472
  - doping, 461
  - energy gap, 473
  - lattice parameters, 469
  - layering scheme, 459–460
  - parent compound (LaOFeAs), 465–466, 469, 472, 475–476
  - penetration depth, 475
  - phase diagram, 466
  - resistivity, 476
  - synthesis, 478
  - upper critical field, 474
- Landau theory, 70
- LaOFeAs (*see* La-1111)
- Laue method, 104–105
- lattice parameters
- Bi-2212, 111
  - (Bi,Pb)-2223, 111
  - cuprate superconductors (table), 126–127
  - Fe-based superconductors, 459–460
    - (1 1 1 1) family, 469
    - Ba-122, 469
    - FeSe, 469
    - LiFeAs, 469
  - Hg-1201, 123
  - Hg-1212, 125
  - Hg-1223, 125
  - Hg-1234, 125
  - Hg-12( $n-1$ ) $n$ , 127
  - La<sub>2</sub>CuO<sub>4</sub>, 89, 107
  - MgB<sub>2</sub>, 424
  - Tl-2201, 114
  - Tl-2212, 116
  - Tl-2223, 116, 118
  - Tl-2234, 118
  - Tl-12( $n-1$ ) $n$ , 127
  - YBa<sub>2</sub>Cu<sub>3</sub>O<sub>7</sub>, 89
- lattice vibrations (*see* phonons)
- layering schemes (cuprate superconductors), 88–91
- HgBa<sub>2</sub>Ca <sub>$n-1$</sub> Cu <sub>$n$</sub> O <sub>$2n+2$</sub>  (Hg-12( $n-1$ ) $n$ ), 89, 91
  - La<sub>2</sub>CuO<sub>4</sub>, 88
  - Tl<sub>2</sub>Ba<sub>2</sub>Ca <sub>$n-1$</sub> Cu <sub>$n$</sub> O <sub>$2n+4$</sub>  (Tl-22( $n-1$ ) $n$ ), 89–90
  - YBa<sub>2</sub>Cu<sub>3</sub>O<sub>7</sub>, 88
- layering schemes (Fe-based superconductors), 459–460
- (1 1) family, 459–460
  - (1 1 1) family, 459–460
  - (1 1 1 1) family, 459–460
  - (1 2 2) family, 459–460





## Subject Index 509

- LiFeAs (Li-111), 459–460, 462, 470, 473, 475, 479  
 coherence length, 475  
 critical temperature, 462  
 energy gap, 473  
 lattice parameters, 470  
 layering scheme, 459–460  
 penetration depth, 475  
 synthesis, 479
- London equations, 3, 31–32  
 London penetration depth, 3, 26, 27, 32  
 London theory, 2, 4, 26, 32  
 loop currents (*see* orbital currents)  
 Lorentz force, 203, 205, 208, 268, 339  
 low-angle gain boundaries, 188  
 lower critical field ( $B_{c1}$ ), 69, 75  
 cuprates, 165, 174–176  
 table, 175  
 Fe-based superconductors, 473–474  
 table, 474
- magnet applications, 317, 339  
 magnetic bearings, 293, 317  
 magnetic phase diagram, 171–174  
 cuprates, 171–172  
 Type I, 28, 78  
 Type II, 78, 171  
 magnetic relaxation effects, 207  
 logarithmic relaxation, 208  
 nonlogarithmic relaxation, 208  
 relaxation of remanent magnetization, 209–210  
 magnetic resonance imaging (MRI), 345, 492  
 magnetic shielding, 293  
 magnetic susceptibility, 38  
 map of highest critical temperatures, 5  
 Matthieson's rule, 20  
 Mauguin–Hermann symbols, 104  
 Maxwell equations, 31–32  
 mean free path of electrons, 73  
 Meissner effect, 3, 25, 27, 30, 31, 69  
 melt-cast process, 317–318  
 metal-insulator transition, 152  
 $MgB_2$ , 423–450, 489–490  
 coherence length, 432, 433  
 conventional superconductor, 425, 492  
 critical temperature, 423  
 crystal structure, 424  
 electron-phonon interaction, 424  
 energy gap  
 band coupling, 427  
 $\pi$ -band gap, 425–427  
 $\sigma$ -band gap, 425–427  
 Ginzburg–Landau parameter, 432, 433  
 grain-boundary weak links, 423  
 irreversibility field, 430–432  
 irreversibility line, 429–432  
 isotope effect, 424–426  
 partial B isotope effect exponent, 425  
 partial Mg isotope effect exponent, 425  
 lattice parameters, 424  
 penetration depth, 432, 433  
 physical properties (table), 433  
 resistivity, 434–435  
 residual resistivity ratio, 434  
 specific heat, 434, 436–437  
 thermal conductivity, 434, 436  
 two gap superconductor, 425, 426  
 two gaps, 425–427, 490  
 two-gap scenario, 426–428  
 angle-resolved photo electron spectroscopy (ARPES), 426  
 electronic specific heat, 427  
 point-contact Andreev-reflection spectroscopy, 426  
 scanning tunneling spectroscopy, 426  
 specific heat jump, 427–428  
 upper critical field, 428–432  
 angular dependence, 429  
 anisotropy factor, 429  
 evidence for two-gap scenario, 428  
 table, 430  
 XRD pattern, 424–425  
 $\pi$ -band, 425  
 $\sigma$ -band, 425  
 $\sigma$ -band holes, 425
- $MgB_2$  bulk material, 444–446  
 $MgB_2$  films, 446–450  
 critical current densities, 449  
 multilayers, 448–450  
 preparation, 446–448  
 table, 447–448  
 ultrathin films, 448–449
- $MgB_2$  wires and tapes, 437–444  
 critical current densities, 441–444  
*ex situ* route, 437–440  
 high-pressure deformation, 442  
*in situ* route, 437–440  
 mono-core wires, 437–439, 442  
 multifilament wires, 437–439, 442

## 510 Subject Index

- MgB<sub>2</sub> wires and tapes (*continued*)  
 powder, 440, 442  
 powder-in-tube (PIT) method, 437–442  
 sheath materials, 439–440
- Miller–Bravais indices, 102  
 Miller indices, 102–103, 106  
 mixed state, 75, 79–80  
 molecular superconductors, 6  
 Mott insulator, 21, 87, 151–152, 161  
 Mott transition, 21  
 muon spin rotation, 137, 158
- Nd-1111 (NdO<sub>1-x</sub>F<sub>x</sub>FeAs), 462, 464, 474, 476, 478–479  
 critical temperature, 462  
 energy gap, 473  
 irreversibility field, 474  
 resistivity, 476  
 synthesis, 478–479  
 upper critical field, 474
- Néel temperature, 152  
 Nernst coefficient, 268  
 Nernst effect, 158, 160, 265, 268, 273–276  
 vortex Nernst effect, 268  
 neutron diffraction, 106–107  
 neutron scattering, 158  
 NMR spectrometers, 492  
 Nobel prize winners, 2  
 nuclear magnetic resonance (NMR), 137, 158  
 chemical shift, 137  
 Knight shift, 137
- Ohm's law, 31  
 optimum hole concentration (cuprates) (*see* formal valence)  
 orbital currents, 161–162  
 organic superconductor, 6  
 oxalate co-precipitation, 294–295, 297, 299, 303–304,
- pancake vortices, 205  
 paramagnetic susceptibility, 77  
 partial melting process, 341  
 Pauli limiting field, 77  
 Pauli's exclusion principle, 15, 20, 21, 35, 47  
 Pauli spin susceptibility, 77, 137  
 Peltier coefficient, 266  
 Peltier effect, 265–266  
 penetration depth, 32, 72–73, 165–169, 432–433, 475
- cuprates, 165–169  
 Fe-based superconductors, 475  
 MgB<sub>2</sub>, 432, 433
- perfect diamagnetism, 2, 24, 38  
 phonons, 19  
 pinning potential, 207–209  
 powder-in-tube (PIT) method, 341–342, 352, 437–442  
 power applications, 339  
 power transmission cables, 339, 492  
 pressure dependence of  $T_c$   
 (cuprates), 139–145  
 Bi-2212, 140  
 (Bi,Pb)-2223, 140  
 Hg-1201, 142  
 Hg-1212, 142  
 Hg-1223, 142  
 initial pressure derivatives  
 Hg-based cuprate  
 superconductors, 143  
 table, 144  
 Tl-1223, 141  
 Tl-2201, 141  
 Tl-2212, 141  
 Tl-2223, 141  
 uniaxial pressure, 143–145
- probability density, 17  
 processing (cuprate superconductor powders), 293–317 (*see also* synthesis)  
 pseudogap, 151, 158–162  
 pseudogap temperature, 160  
 pyrolysis, 299
- quantum interference effects, 45  
 single SIS contact, 62–64  
 double SIS contact, 64–66
- RABiTS (*Rolling Assisted Biaxially Textured Substrates*), 363–364  
 film sequences, 370  
 yield strength of Ni, 369  
 yield strength of Ni-W, 369
- relative permeability, 38  
 relaxation rate (magnetization), 211  
 relaxation time, 19  
 residual resistivity, 1, 20  
 residual resistivity ratio RRR (definition), 20  
 resistivity, 20–21  
 intrinsic (metals), 20



- upper limit in superconducting state, 23–24
  - resistivity (normal state)
    - cuprate superconductors, 232–249
      - anisotropy of resistivity, 239–241
      - anisotropy ratios, 239, 241
      - Bi-based cuprates, 233–234
        - in-plane anisotropy (Bi-2212), 233, 239–240
      - effect of heat treatments, 234, 236–237
      - Hg-based cuprates, 234–235
      - irradiation effects on  $T_c$ , 238–239
      - $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$  (sintered), 232–233
      - RE-123, 234, 236
      - relation with pseudogap
        - temperature, 241, 248–249
      - table, 242–247
      - Tl-based cuprates, 234–235
    - Fe-based superconductors, 475–477
    - $\text{MgB}_2$ , 434–435
  - Rutger's formula, 40
  - Rutherford cables (Ag/Bi-2212), 351
- 
- Scanning tunneling microscopy (STM), 170
  - scanning tunneling spectroscopy (STS), 158, 159
  - Schottky anomaly, 279
  - Schottky barrier, 191–193
  - Schottky contribution (see Schottky specific heat)
  - Schottky specific heat, 280, 289
  - Schrödinger equation, 14, 17
  - screening currents, 24
    - thin superconducting slab, 34–35
  - Seebeck coefficient, 265–266, 269–273
  - Seebeck effect, 265
  - Shubnikov phase (see mixed state)
  - Sm-1111 ( $\text{SmO}_{1-x}\text{F}_x\text{FeAs}$ ), 6, 459, 461–463, 466, 468, 473, 474
    - critical temperature, 459, 461–463
    - energy gap, 473
    - lattice parameters, 469
    - penetration depth, 475
    - phase diagram, 466
    - resistivity, 476
    - upper critical field, 474
  - small-angle grain boundaries, 355
  - solid-state reaction, 294–295, 298–300, 302, 305, 311
  - space charge region, 191–193
  - space charge effects, 192
  - space group, 104
  - space group symbol, 104
  - specific heat
    - cuprates
      - low temperature specific heat, 280–283
        - Bi-2212, 281, 282
        - (Bi,Pb)-2223, 281, 283
        - Hg-1201, 283
        - $\text{La}_2\text{CuO}_4$ , 283
        - Y-123, 280, 281
        - Y-124, 283
        - Y-247, 283
      - specific heat jump at  $T_c$ , 284–286
        - Bi-2212, 284, 285
        - (Bi,Pb)-2223, 284, 285
        - Dy-123, 284
        - Gd-123, 284, 285
        - in-field data, 284
        - Tl-2223, 284, 285
        - Y-124, 284, 285
        - Y-123, 284, 285
      - specific heat data up to room temperature, 287–288
    - Debye approximation, 34–35, 279
    - electron contribution (electron-specific heat), 35–36
    - jump in specific heat at  $T_c$ , 40–41, 280
    - normal state, 35–36
      - at low temperatures, 37
    - phonon contribution (phonon-specific heat), 34–36, 279
  - Sr-122, 462, 481
    - critical current density, 481
    - critical temperature, 462
  - standard enthalpies of formation (Bi-Sr-Ca-Cu-O system), 298
  - strong links, 180, 355
  - structure factor, 106
  - superconducting elements, 29, 30
    - $T_c$  under high pressure, 30
  - superconducting order parameter, 151–152
    - antinodal direction, 159, 162
    - $d$ -wave symmetry, 151–154, 162
    - extended  $s$ -wave, 490
    - nodal direction, 152, 159, 162
    - $s$ -wave symmetry, 151–154

512 *Subject Index*

- superconductivity
  - discovery, 1–4
  - macroscopic quantum phenomenon, 3, 45–66
  - milestones in history of
    - superconductivity, 2
- superconductor thermodynamics, 34–42
  - entropy, 38–40
  - Gibbs free energy, 34, 36
  - Gibbs free energy of normal state, 37, 39
  - Gibbs free energy of superconducting state, 38, 39
  - internal energy, 36
  - normal state entropy, 37
  - specific heat, 39–41
- surface energy, 72, 73
- synthesis (cuprate superconductor powders), 293–317
  - Bi-based superconductors, 296–303
    - Bi-2212, 296–299
      - oxalate co-precipitation, 299
      - pyrolysis, 299
      - solid-state reaction, 298–299
      - table, 299
    - (Bi,Pb)-2223, 296, 298–303
      - freeze-dried nitrate solutions, 302
      - heat treatment atmosphere, 300
      - oxalate co-precipitation, 303, 304
      - partial lead substitution, 300
      - solid-state reaction, 300, 302
      - two-powder process, 300, 302
  - Hg-based superconductors, 311–317
    - Hg-1201, 311–313
    - Hg-1212, 313, 314
    - Hg-1223, 313, 315, 316
    - Hg-1234, 313
    - solid-state reaction, 311
  - Tl-based superconductors, 303–311
    - Tl-1212, 305, 306, 308
    - Tl-1223, 305, 306, 309, 310
    - Tl-2201, 304, 305
    - Tl-2212, 305, 306
    - Tl-2223, 305, 307, 308
    - Tl-2234, 305
    - two-step synthesis routes, 303–304
  - Y-based superconductors, 294–296
    - citrate pyrolysis, 294, 296
    - oxalate co-precipitation, 294–295, 297
    - solid-state reaction, 294–295
- thermal conductivity (cuprates), 249–256
  - anisotropy, 253, 255
  - bulk cuprate superconductors, 253, 254
  - effect of applied magnetic field, 255, 256
  - electronic contribution, 250, 251
  - measurement, 251, 253
  - melt-textured Y-123, 253
  - phonon contribution, 249, 250
  - polycrystalline cuprate
    - superconductors, 251–252
    - aligned (Bi,Pb)-2223, 252
    - single crystals, 253–255
- thermally activated flux creep, 203, 207–216
- thermocouple, 266, 267
- thermopower (thermoelectric power), 265
  - cuprates, 269–273
- Thomas–Fermi screening length, 191
- Thomson coefficient, 266
- Thomson effect, 265, 266
- Thomson relations, 268
- tilt grain boundaries, 190
- Tl-1212, 305, 306, 308
- Tl-1223, 119–121, 141, 304–306, 309, 310
  - copper oxide blocks, 119
  - crystal structure, 119–121
    - atom positions, 121
  - initial  $dT_c/dp$ , 141
  - powder synthesis, 304–306, 309, 310
  - XRD pattern, 120
- Tl-2201, 89, 114–116, 140, 141, 304, 305
  - copper oxide blocks, 114, 115
  - crystal structure, 114–116
    - atom positions, 116
  - initial  $dT_c/dp$ , 141
  - lattice parameters, 114
  - powder synthesis, 304, 305
  - XRD pattern, 115
- Tl-2212, 116–118, 140, 141, 305, 306
  - copper oxide blocks, 116, 117
  - crystal structure, 116, 117
    - atom positions, 117
  - initial  $dT_c/dp$ , 141
  - lattice parameters, 116
  - powder synthesis, 305, 306
  - XRD pattern, 116
- Tl-2223, 116, 118–120, 140, 141, 284, 285, 305, 307, 308
  - crystal structure, 116, 118–120
    - atom positions, 120



## Subject Index 513

- initial  $dT_c/dp$ , 141
- lattice parameters, 116, 118
- powder synthesis, 305, 307–308
- specific heat, 284, 285
- XRD pattern, 118
- transformers, 339, 492
- transition temperature, see critical temperature
- tri-crystal superconducting rings, 154, 155
  - zero ring, 155
  - $\pi$ -ring, 154, 155
- tunneling, 52–66
  - single electron tunneling (NIN), 54–56
  - single electron tunneling (NIS), 56–58
  - single electron tunneling (SIS), 56, 57, 59, 60, 62, 64, 65
- tunneling experiments, 4
- tunneling spectra of Bi-2212, 158
- two-gap scenario (see  $\text{MgB}_2$ )
- two-gap superconductor (see  $\text{MgB}_2$ )
- Type I superconductors, 69, 72–81
  - critical current, 81–83
- Type II superconductors, 69–84
  - critical current, 81–83
- upper critical field ( $B_{c2}$ ), 69, 75
  - cuprate superconductors, 165, 173–175
    - table, 175
  - Fe-based superconductors, 473, 474
    - table, 474
  - $\text{MgB}_2$ , 428–434
    - angular dependence, 429
    - anisotropy factor, 429
    - evidence for two-gap scenario, 427, 428
    - table, 430
- valence band, 17, 18
- Vickers micro hardness, 346
- vortex–vortex interaction, 79, 204
- vortices, 79, 81–83, 160, 205, 206, 268, 274
- weak-link behavior, 191
- weak-link problem, 317, 361, 489, 491
- weak links (grain boundaries), 180, 188–193
- Werthamer-Helfand-Hohenberg (WHH) theory, 173, 473
- Wiedemann–Franz law, 250, 251
- X-ray diffraction, 104–106
  - rocking curve, 354, 355
- X-ray powder diffraction, 105–106
- X-ray powder diffraction pattern (XRD pattern)
  - $\text{BaFe}_{1.87}\text{Co}_{0.13}\text{As}_2$ , 470
  - $\text{Ba}_{0.6}\text{K}_{0.4}\text{Fe}_2\text{As}_2$ , 470
  - Bi-2212, 112
  - (Bi,Pb)-2223, 112
  - $\text{CeO}_{0.84}\text{F}_{0.16}\text{FeAs}$ , 469
  - FeSe, 471
  - FeTe, 471
  - Hg-1201, 122
  - Hg-1212, 123
  - Hg-1223, 123
  - $\text{LaO}_{0.8}\text{F}_{0.2}\text{FeAs}$ , 468
  - $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$ , 107
  - LiFeAs, 470
  - $\text{MgB}_2$ , 424
  - $\text{Sm}_{0.85}\text{F}_{0.15}\text{FeAs}$ , 468
  - Tl-1223, 120
  - Tl-2201, 115
  - Tl-2212, 116
  - Tl-2223, 118
  - Tl-2234, 118
  - $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$ , 110
- Y-123
  - crystal structure, 108–111
    - atom positions, 111
  - CuO chains, 110
  - dependence of  $T_c$  on formal Cu valence, 132, 133
  - multilayers (Pr-123-Y-123), 407, 408
  - specific heat, 280, 281, 284, 285
  - thermal conductivity, 253
  - tri-layers (Pr-123-Y-123-Pr-123), 408, 409
  - XRD pattern, 110

